

Single 2-Input Exclusive-OR Gate

NLV17SZ86

The NLV17SZ86 is a high performance single 2-input Exclusive-OR Gate in tiny footprint packages.

Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- 2.9 ns t_{PD} at $V_{CC} = 5 \text{ V (typ)}$
- Inputs/Outputs Overvoltage Tolerant up to 5.5 V
- I_{OFF} Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.0 V
- Available in SC-88A and SOT-953 Packages
- Chip Complexity < 100 FETs
- ORDERING:

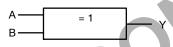
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 page 7 of this data sheet.

 Symbol

 Symbol

 REPRESENTATIVE

 REPRESENTA • NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



MARKING DIAGRAMS



SC-88A **DF SUFFIX** CASE 419A





SOT-953 **P5 SUFFIX CASE 527AE**



XX = Specific Device Code

М = Date Code*

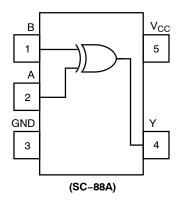
= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information on



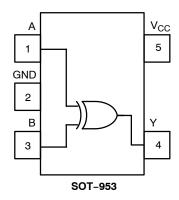


Figure 2. Pinout (Top View)

PIN ASSIGNMENT (SC-88A)

Pin	Function
1	В
2	Α
3	GND
4	Y
5	V _{CC}

PIN ASSIGNMENT (SOT-953)

PIN ASSIGNMENT (SOT-953)					
Pin	Function	"CM			
1	A	2510			
2	GND) -			
3	В				
4	N / Y				
5	V _{cc}	7			

		D D		'	
	2	Α		2	GND
	3	GND		3	В
	4	Υ		4	N M
	5	V _{CC}		5	V _{CC}
	SEIS	FUNCTION TAE	B H H	Output Y H H L	onsernation ORMATION
	ENIO, Br	RESERVE			
THISD	REP				

MAXIMUM RATINGS

Symbol	Char	Value	Unit	
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage	Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode (V_{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +7.0 -0.5 to +7.0	V
	DC Output Voltage	(NL17SZ86P5T5G-L22088 Only)	-0.5 to V _{CC} + 0.5	
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-50	mA
	DC Output Diode Current	(NL17SZ86P5T5G-L22088 Only)	±50	
I _{OUT}	DC Output Source/Sink Current		±50	mA
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or	Ground Pin	±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	J ∘C
T _L	Lead Temperature, 1 mm from Case	for 10 secs	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SC-88A SOT-953	377 254	°C/W
P _D	Power Dissipation in Still Air	SC-88A SOT-953	332 491	mW
MSL	Moisture Sensitivity	.0	Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I _{Latchup}	Latchup Performance (Note 4)	1 00hill 1/hi	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.

2. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.

3. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.

4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics			Max	Unit
V _{CC}	Positive DC Supply Voltage		1.65	5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	0 0 0	V _{CC} 5.5 5.5	V
	DC Output Voltage	(NL17SZ86P5T5G-L22088 Only)	0	V _{CC}	
T _A	Operating Temperature Range		-55	+125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 3.0 V to 3.6 V V _{CC} = 4.5 V to 5.5 V	0 0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

			v _{cc}	T _A = 25°C		-55°C ≤ T _A ≤ 125°C			
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	High-Level Input		1.65 to 1.95	0.75 x V _{CC}	7	-	0.75 x V _{CC}	-	V
	Voltage		2.3 to 5.5	0.70 x V _{CC}	-	-11	0.70 x V _{CC}	-	
V _{IL}	Low-Level Input		1.65 to 1.95	-		0.25 x V _{CC}	-	0.25 x V _{CC}	V
	Voltage		2.3 to 5.5	-	- F	0.30 x V _{CC}	" Ob	0.30 x V _{CC}	
V _{ОН}	High-Level Output Voltage	$\begin{split} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OH} &= -100 \mu\text{A} \\ I_{OH} &= -4 \text{ mA} \\ I_{OH} &= -8 \text{ mA} \\ I_{OH} &= -12 \text{ mA} \\ I_{OH} &= -16 \text{ mA} \\ I_{OH} &= -24 \text{ mA} \\ I_{OH} &= -32 \text{ mA} \end{split}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V _{CC} = 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V _{CC} 1.4 2.1 2.4 2.7 2.5 4.0	ORMA	V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	111111	>
V _{OL}	Low-Level Output Voltage	$\begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 100 \mu\text{A} \\ I_{OL} = 4 m\text{A} \\ I_{OL} = 8 m\text{A} \\ I_{OL} = 12 m\text{A} \\ I_{OL} = 16 m\text{A} \\ I_{OL} = 24 m\text{A} \\ I_{OL} = 32 m\text{A} \end{array}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5		- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55	- - - - -	0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND	1.65 to 5.5	-	_	±0.1	-	±1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0	_	-	1.0	-	10	μΑ
	Power Off Leakage Current (NL17SZ86P5T5G- L22088 Only)	V _{IN} = 5.5 V	0	-	-	1.0	-	10	μΑ
I _{CC}	Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5	-	-	1.0	-	10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

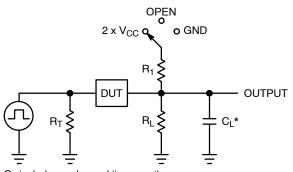
AC ELECTRICAL CHARACTERISTICS

			V _{CC}	T,	A = 25°	С	-55°C ≤ T	_A ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
t _{PLH,} Propagation Delay,	$R_L = 1 M\Omega$, $C_L = 15 pF$	1.65 to 1.95	-	6.9	13.8	-	14.5	ns	
₹PHL	t _{PHL} (A or B) to Y (Figures 3 and 4)	$R_L = 1 M\Omega$, $C_L = 15 pF$	2.3 to 2.7	_	4.1	7.0	_	7.5	
		$R_L = 1 M\Omega$, $C_L = 15 pF$	3.0 to 3.6	-	3.0	4.8	-	5.2]
		$R_L = 500 \Omega$, $C_L = 50 pF$	_	3.8	5.4	_	5.9		
	$R_L = 1 M\Omega$, $C_L = 15 pF$	4.5 to 5.5	_	2.2	3.5	_	3.8		
		$R_L = 500 \Omega$, $C_L = 50 pF$		-	2.9	4.2	-	4.6	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	2.5	pF
C _{OUT}	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V_{CC} = 3.3 V, V_{IN} = 0 V or V_{CC} 10 MHz, V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	9 11	pF

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.



Test	Switch Position	C _L , pF	R_L, Ω	R ₁ , Ω	
t _{PLH} / t _{PHL}	Open	See AC Characteristics Table			
t _{PLZ} / t _{PZL}	2 x V _{CC}	50	500	500	
t _{PHZ} / t _{PZH}	GND	50	500	500	

X = Don't Care

C_L includes probe and jig capacitance

 R_T is Z_{OUT} of pulse generator (typically 50 Ω) f=1 MHz

Figure 3. Test Circuit

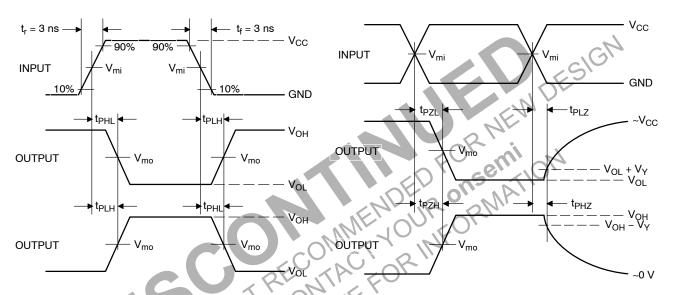


Figure 4. Switching Waveforms

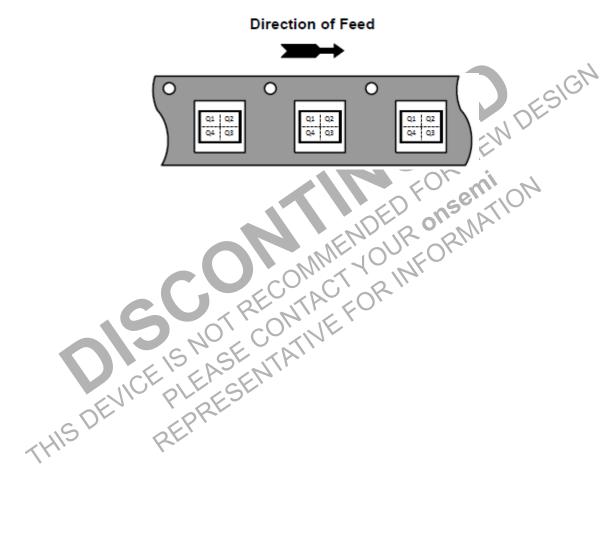
	INCOME SE	V _m		
V _{CC} , V	V _{mi} , V	t _{PLH} , t _{PHL}	t_{PZL} , t_{PLZ} , t_{PZH} , t_{PHZ}	V _Y , V
1.65 to 1.95	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
2.3 to 2.7	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
3.0 to 3.6	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3
4.5 to 5.5	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3

DEVICE ORDERING INFORMATION

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping [†]
NLV17SZ86DFT2G*	SC-88A	L8	Q4	3000 / Tape & Reel
NL17SZ86P5T5G-L22088	SOT-953	P (Rotated 180° CW)	Q2	8000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PIN 1 ORIENTATION IN TAPE AND REEL



^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.





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SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

DATE 11 APR 2023

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE, NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

DIM	MILLIMETERS				
INITU	MIN.	N□M.	MAX.		
А	0.80	0.95	1.10		
A1			0.10		
A3	0,20 REF				
b	0.10	0.20	0.30		
C	0.10		0.25		
D	1.80	2.00	2,20		
Е	2.00	2.10	2.20		
E1	1.15	1.25	1.35		
е	0.65 BSC				
L	0.10 0.15 0.30				

5X b

◆ 0.2 M B M

- PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

	L → 	
<u> </u>	0.50	5

RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

5. COLLECTOR

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	2. EMITTER	2. N/C	2. DRAIN 1/2	2. COMMON ANODE
3. BASE	3. BASE	3. ANODE 2	SOURCE 1	3. CATHODE 2
4. COLLECTOR	COLLECTOR	CATHODE 2	4. GATE 1	4. CATHODE 3
COLLECTOR	CATHODE	CATHODE 1	5. GATE 2	5. CATHODE 4
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	Note: Please refer to datasheet for
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	atula callout. If atula tupa is not called
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	style callout. If style type is not called
EMITTER 1	3. BASE	3. N/C	3. ANODE	out in the datasheet refer to the device
4. COLLECTOR	COLLECTOR	4. BASE	4. ANODE	datasheet pinout or pin assignment.
COLLECTOR 2/BASE 1	5. COLLECTOR	5. EMITTER	5. ANODE	datasheet pinout of pin assignment.

DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	
DESCRIPTION:	SC-88A (SC-70-5/SOT-353)		PAGE 1 OF 1

5. EMITTER

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5. COLLECTOR 2/BASE 1

MILLIMFTERS

 $N\square M$

0.37

0.15

0.12

1.00

0.80

0.35 BSC

1.00

0.175

0.10

(REF)

-0.350

0.075

-0.200

MIN

0.34

0.10

0.07

0.95

0.75

0.95

0.125

0.05

DIM

Α

b

C

 \mathbb{D}

E

9 Н

L2

L3





SOT-953 1.00x0.80x0.37, 0.35P CASE 527AE **ISSUE F**

DATE 17 JAN 2024

MAX

0.40

0.20

0.17

1.05

0.85

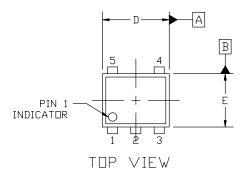
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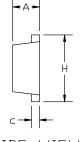
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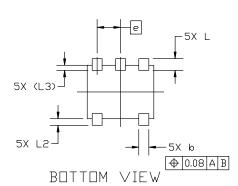
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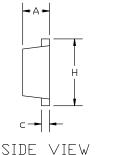
NOTES:

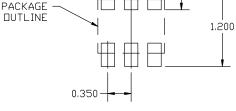
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.











RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

GENERIC MARKING DIAGRAM*



= Specific Device Code

= Month Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON26457D	Electronic versions are uncontrolled except when accessed directly fron Printed versions are uncontrolled except when stamped "CONTROLLEI	
DESCRIPTION:	SOT-953 1.00x0.80x0.37, 0.35P		PAGE 1 OF 1

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